

گروه فنی مهندسی جوش و برش مقدم

اعتماد از شما کیفیت و تخصص از ما



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مشهد خيام شمالي 63 خيابان پرديس 3

برای کسب اطلاعات بیشتر بر روی لینک ها کلیک کنید

- 7 سال سابقه آموزش تعمیرات تخصصی دستگاه های جوش اینورتری تک فاز و 3 فاز
- 7 سال سابقه فروش قطعات الکترونیکی دستگاه جوش
 تک فاز و 3 فاز
- آموزش تخصصی تحلیل دستگاه های جوش اینورتری مختص ابراز فروشان
 - آموزش تخصصی ابراز آلات شارژی





RJH60F7BDPQ-A0

600V - 50A - IGBT High Speed Power Switching

Datasheet

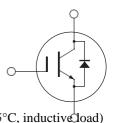
R07DS0633EJ0100 Rev.1.00Feb 17, 2012

Features

- Low collector to emitter saturation $V_{CE(sat)} = 1.35 \text{ V}$ typ. (at $I_C = 50 \text{ A}$,
- Built in fast recovery diode in one page
- Trench gate and thin wafer technology
- High speed switching

 $t_f = 74 \text{ ns typ.}$ (at $I_C = 30 \text{ A}$, $V_{CE} = 400 \text{ V}$, $V_{GE} = 15 \text{ V}$, $Rg = 5 \Omega$, $Ta = 25 ^{\circ}\text{C}$, inductive load)





Outline

Absolute Maximum Ratings

 $(Tc = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage		V _{CES}	600	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	Tc = 25°C	Ic	90	Α
	Tc = 100°C	Ic	50	А
Collector peak current		ic(peak) Note1	180	А
Collector to emitter diode forward peak current		i _{DF} (peak) Note2	100	Α
Collector dissipation		Pc	328.9	W
Junction to case thermal impedance (IGBT)		θј-с	0.38	°C/W
Junction to case thermal impedance (Diode)		θj-cd	1.1	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. Pulse width limited by safe operating area.

2. $PW \le 5 \mu s$, duty cycle $\le 1\%$

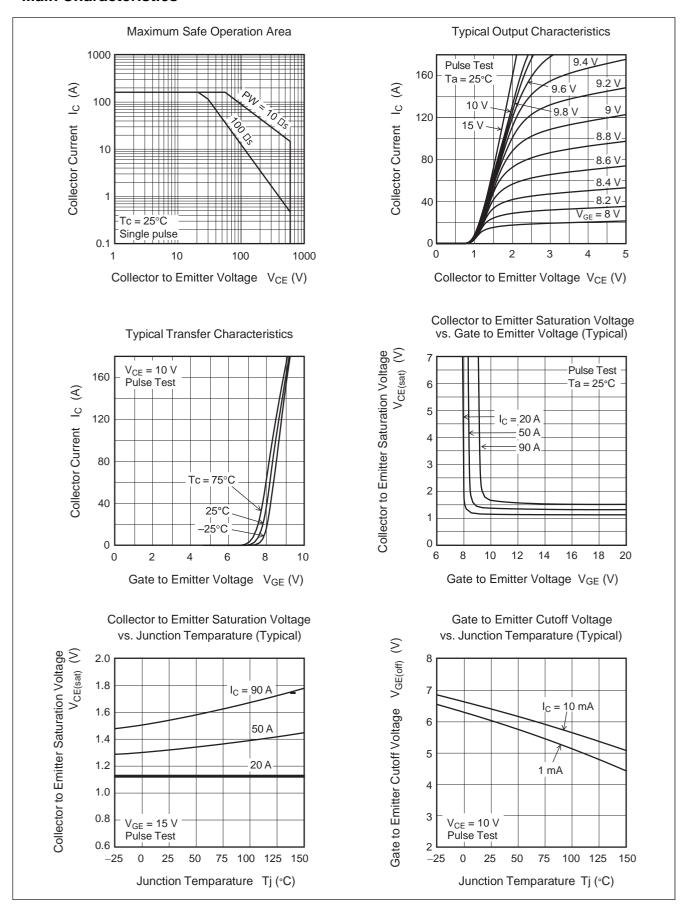
Electrical Characteristics

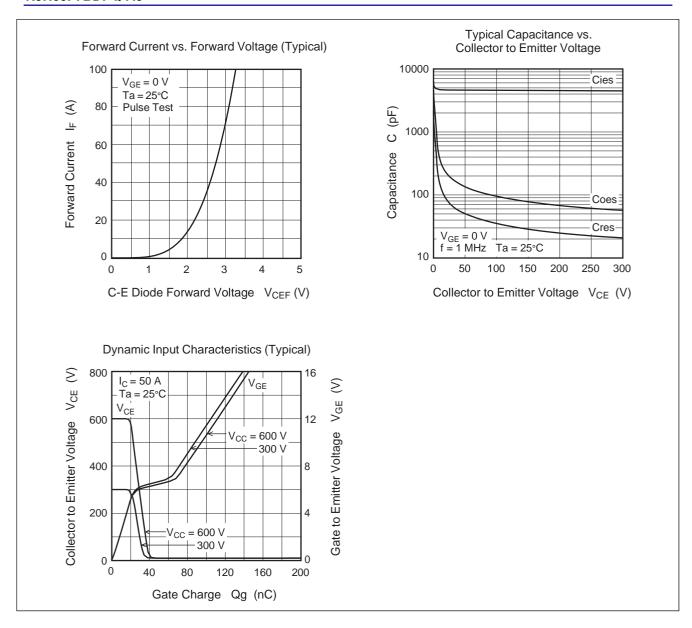
 $(Tj = 25^{\circ}C)$

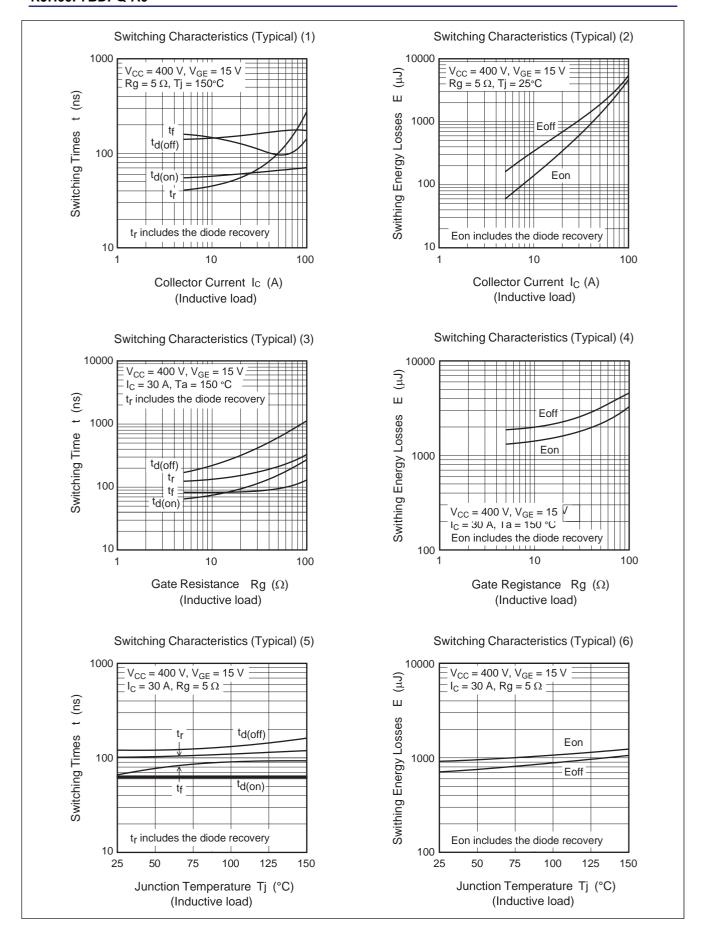
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current	I _{CES}	_	_	100	μΑ	V _{CE} = 600V, V _{GE} = 0
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{GE(off)}$	4	_	8	V	$V_{CE} = 10V, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.35	1.75	V	Ic = 50 A, V _{GE} = 15V Note3
	V _{CE(sat)}	_	1.6	_	V	$I_C = 90 \text{ A}, V_{GE} = 15 V^{\text{Note3}}$
Input capacitance	Cies	_	4700	_	pF	V _{CE} = 25 V V _{GE} = 0 V f = 1 MHz
Output capacitance	Coes	_	198	_	pF	
Reverse transfer capacitance	Cres	_	83	_	pF	
Switching time	t _{d(on)}	_	63	_	ns	I_{C} = 30 A, V_{CE} = 400 V, V_{GE} = 15 V Rg = 5 Ω Note3 Inductive load
	tr	_	81	_	ns	
	t _{d(off)}	_	142	_	ns	
	t _f	_	74	_	ns	
C-E diode forward voltage	V_{ECF}	_	2.5	3.0	V	I _F = 30 A Note3
C-E diode reverse recovery time	t _{rr}	_	25	_	ns	I _F = 30 A
						di _F /dt = 100 A/μs

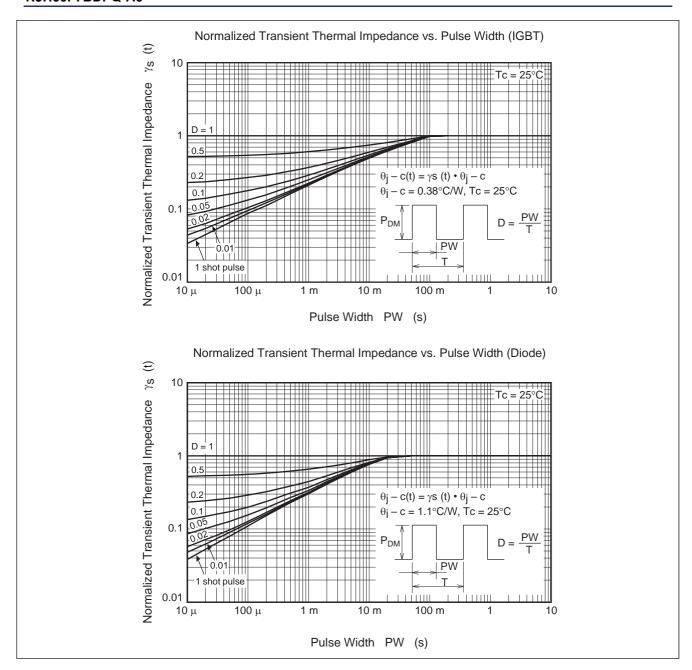
Notes: 3. Pulse test

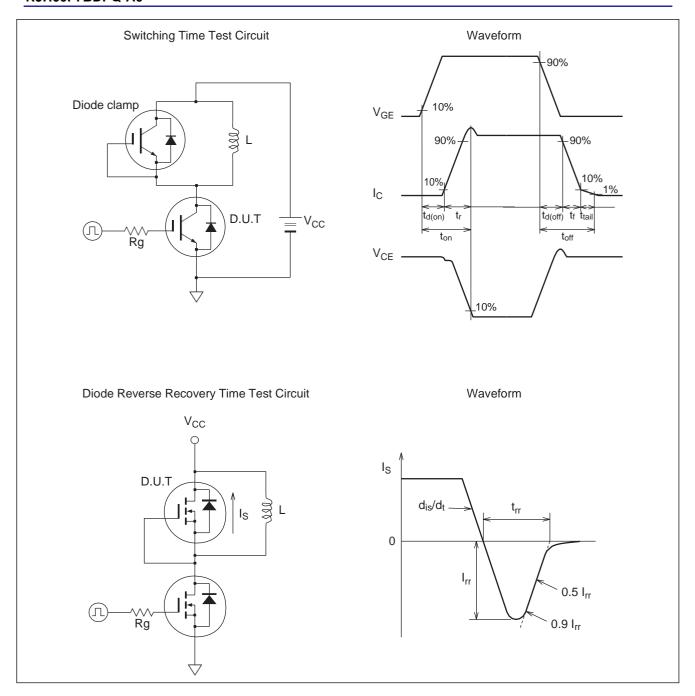
Main Characteristics



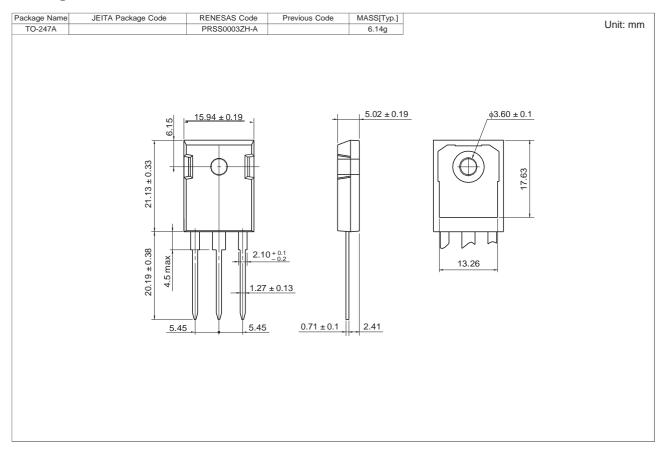








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60F7BDPQ-A0#T0	240 pcs	Box (Tube)

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